

ROUND TYPE LED LAMPS



LH3330-PF

DATA SHEET

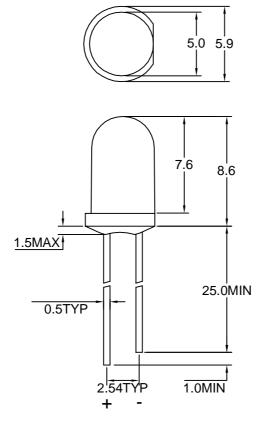
DOC. NO: QW0905-LH3330-PF

REV. : A

DATE : 25 - Jun - 2005

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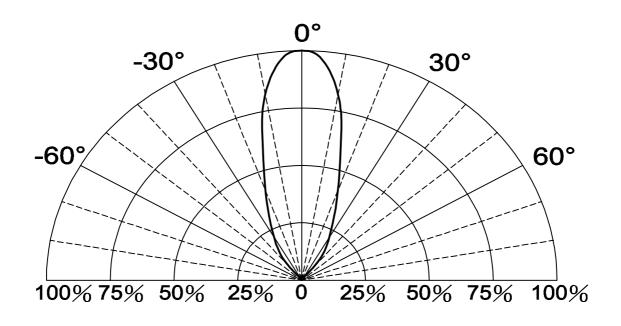
Package Dimensions



Note: 1.All dimension are in millimeter tolerance is ±0.25mm unless otherwise noted.

2. Specifications are subject to change without notice.

Directivity Radiation





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Absolute Maximum Ratings at Ta=25

Parameter	Symbol	Ratings	LIAUT
Parameter		Н	UNIT
Forward Current	lF	15	mA
Peak Forward Current Duty 1/10@10KHz	lfp	60	mA
Power Dissipation	PD	40	mW
Reverse Current @5V	lr	10	μА
Operating Temperature	Topr	-40 ~ +85	
Storage Temperature	Tstg	-40 ~ +100	
Soldering Temperature	Tsol	Max 260 for 5 sec Max (2mm from body)	

Typical Electrical & Optical Characteristics (Ta=25)

PART NO MATERIAL		COLOR		Peak wave length Pnm	Spectral halfwidth nm	Forward voltage @20mA(V)		Luminous intensity @10mA(mcd)		Viewing angle 2 1/2 (deg)
		Emitted	Lens			Min.	Max.	Min.	Тур.	
LH3330-PF	GaP	Red	Red Diffused	697	90	1.7	2.6	3.0	4.5	36

Note : 1. The forward voltage data did not including $\pm 0.1 \text{V}$ testing tolerance.

^{2.} The luminous intensity data did not including ±15% testing tolerance.



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Typical Electro-Optical Characteristics Curve

H CHIP

Fig.1 Forward current vs. Forward Voltage

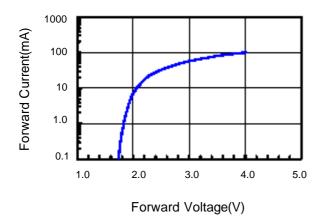
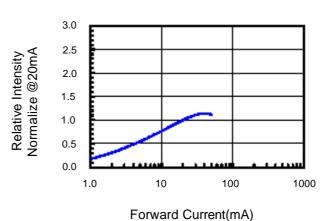
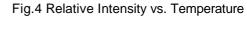
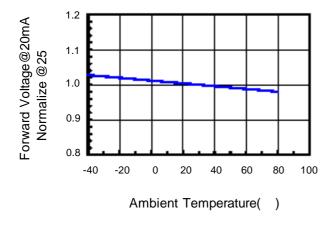


Fig.2 Relative Intensity vs. Forward Current









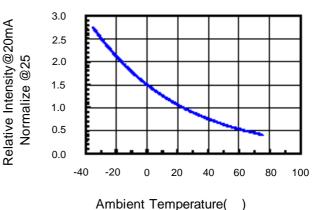
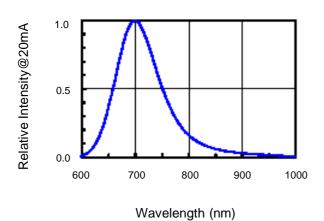


Fig.5 Relative Intensity vs. Wavelength





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Soldering Condition(Pb-Free)

1.Iron:

Soldering Iron:30W Max Temperature 350°C Max

Soldering Time: 3 Seconds Max(One Time)
Distance: 2mm Min(From solder joint to case)

2. Wave Soldering Profile

Dip Soldering

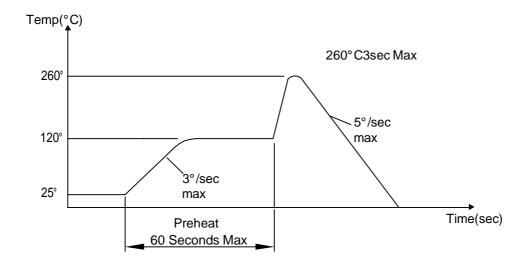
Preheat: 120°C Max

Preheat time: 60seconds Max

Ramp-up 3°C/sec(max)

Ramp-Down:-5° C/sec(max) Solder Bath:260° C Max Dipping Time:3 seconds Max

Distance:2mm Min(From solder joint to case)





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Reliability Test:

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of determining the resisance of a part in electrical and themal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105 ±5 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under ondition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 ±5 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 ±5 2.RH=90 %~95% 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hous.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 ±5 &-40 ±5 (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260 ±5 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=230 ±5 2.Dwell time=5 ±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2